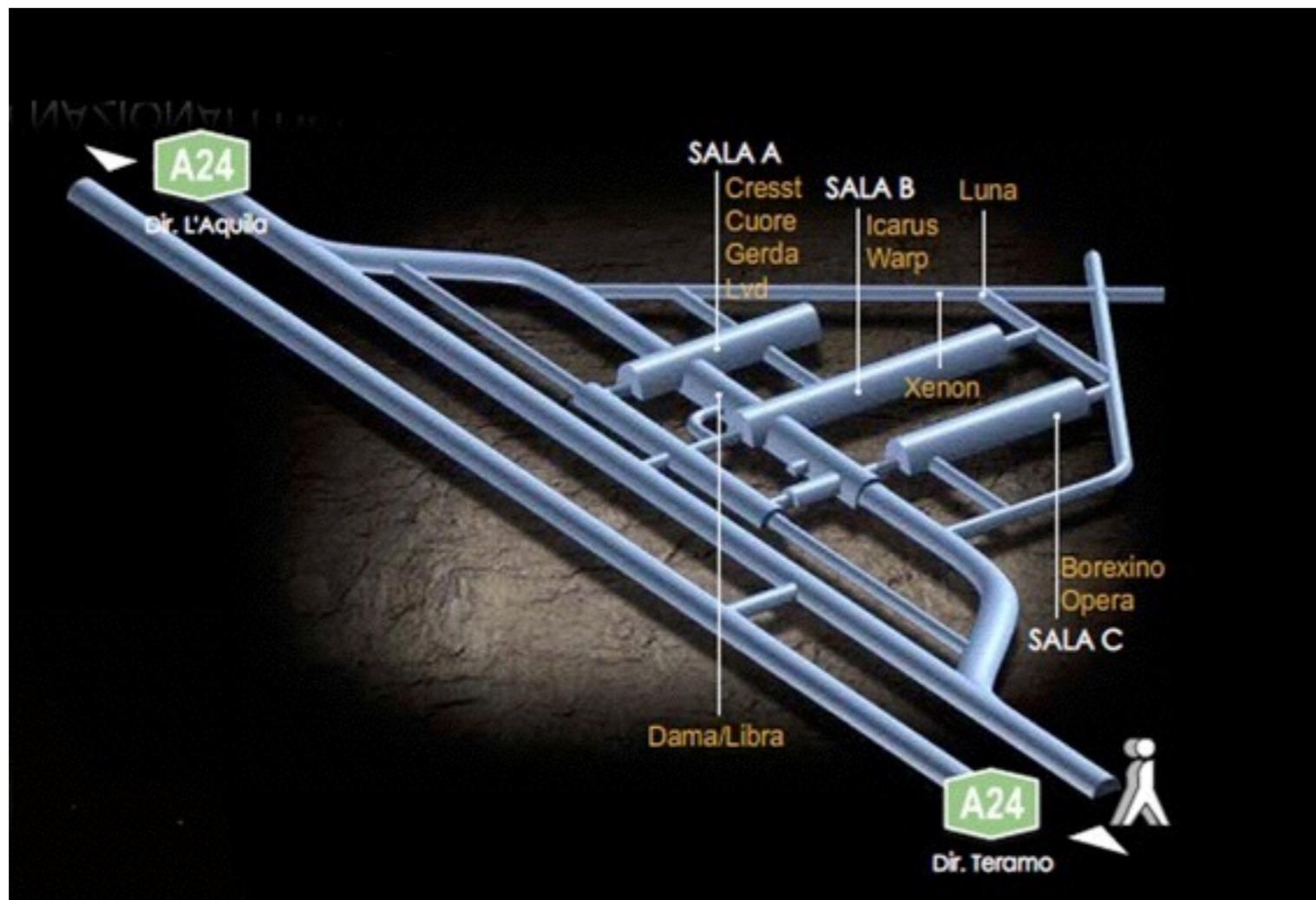


**LAr scintillation light read-out with
SiPMs and WLS fibers
in GERDA**

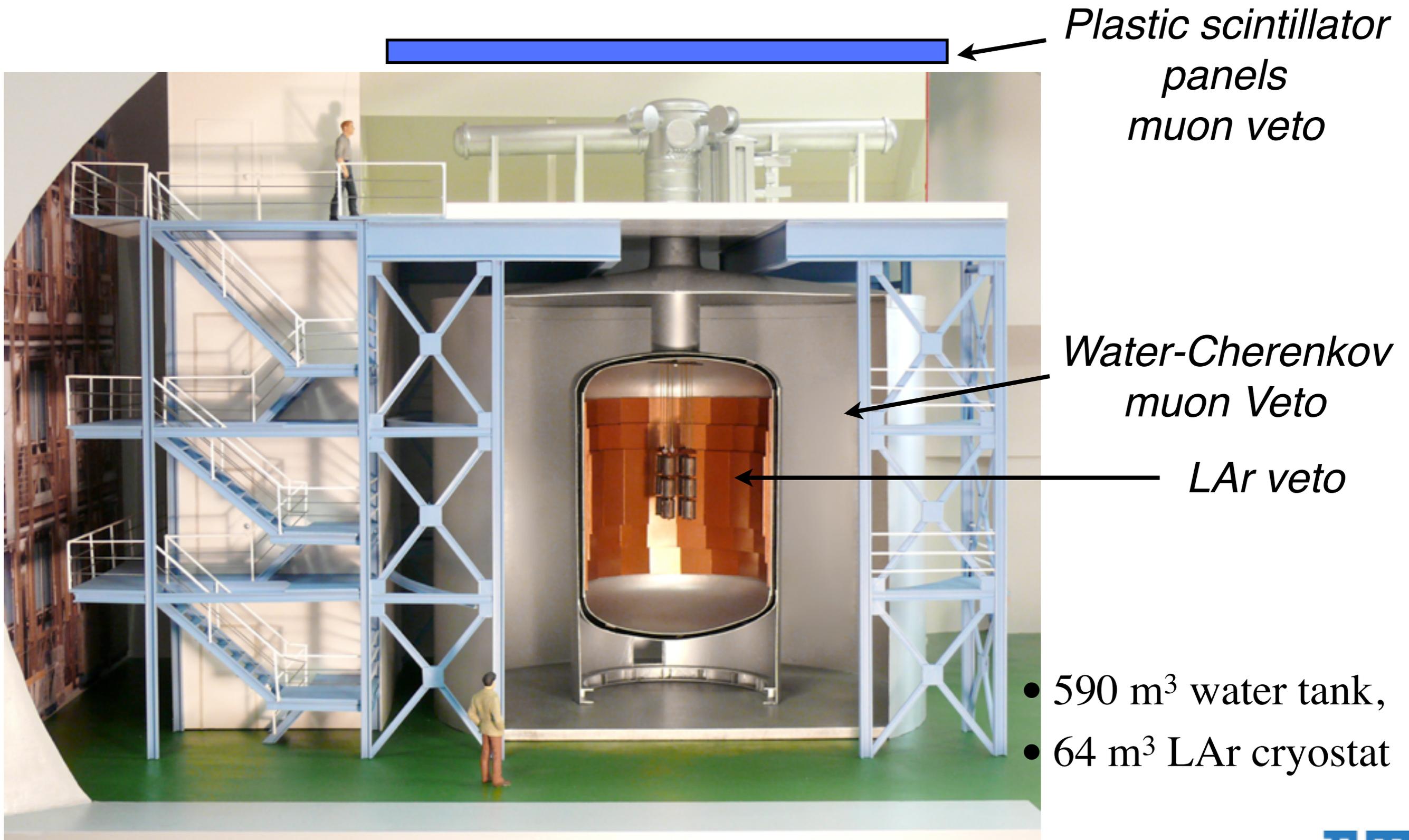
*József, Janicskó Csáthy
Technische Universität München*

GERDA at Gran Sasso

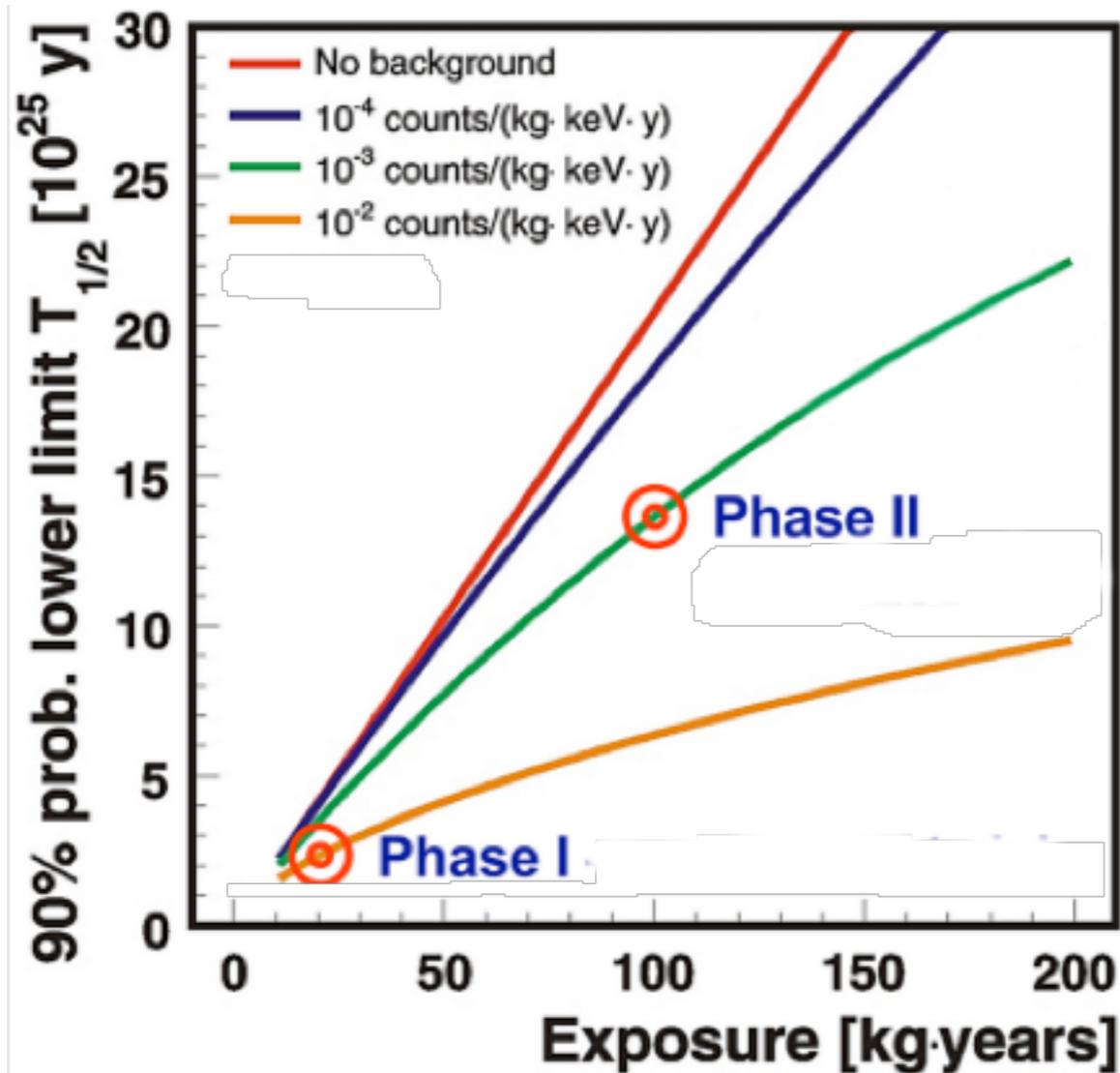
- The GERDA experiment (GERmanium Detector Array) is built for the search of $0\nu\beta\beta$ decay in ^{76}Ge
- is located at INFN - LNGS underground lab. with 3800 m w.e. overburden



GERDA

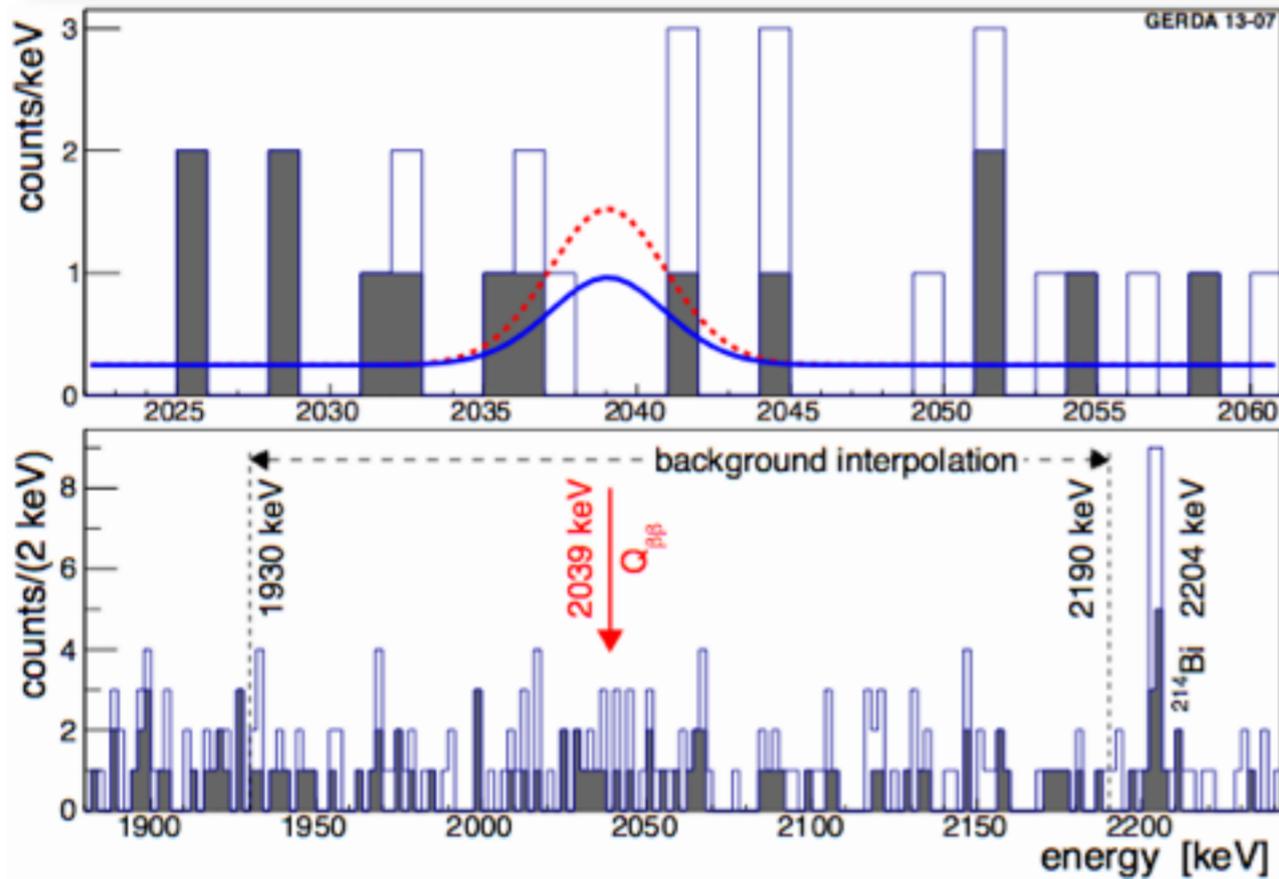


GERDA status



- *Status of Phase I:* data taking ended with 21.6 kg·yr exposure: from Nov. 2011 to May 2013
- *Result of Phase I:* $T_{1/2}^{0\nu} > 2.1 \times 10^{25}$ yr
- *Goal of Phase II:* background level of 0.001 cts/(keV kg yr) and 100 kg yr exposure
- *Phase II strategy to reduce background:* LAr scintillation light readout + pulse shape discrimination
- *Phase II status:* is in commissioning phase right now

GERDA Phase I results



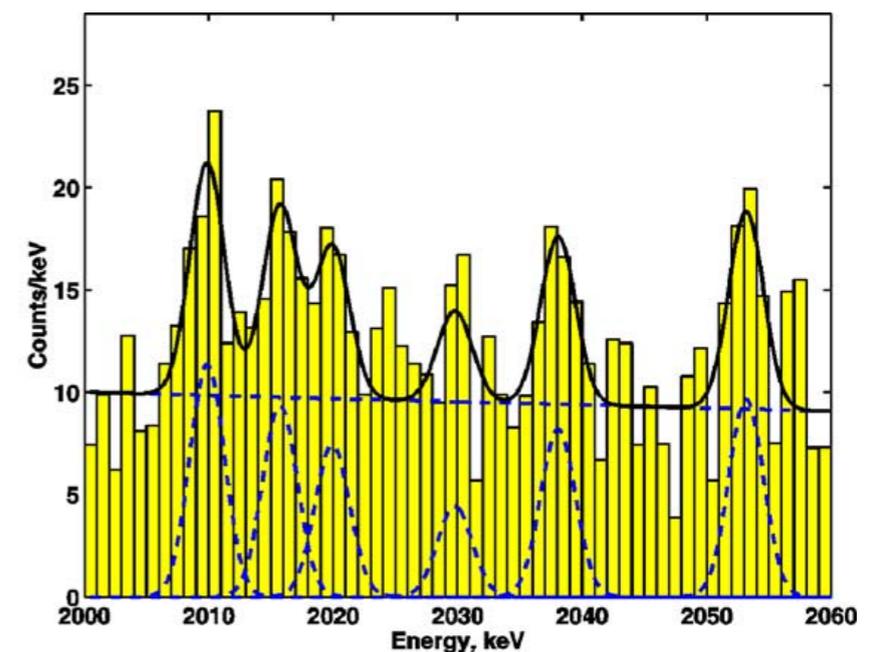
In 2039 ± 5 keV we see 7 counts,
after PSD only 3 remain:

$$T^{0\nu}_{1/2} > 2.1 \times 10^{25} \text{ yr} \\ (90\% \text{ C.L.})$$

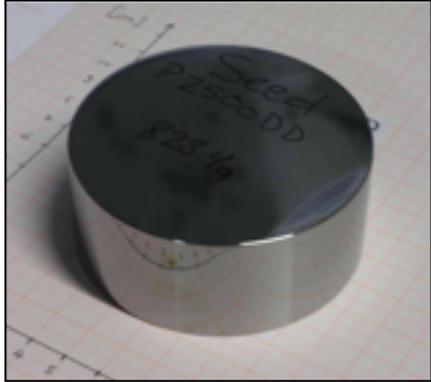
Phys. Rev. Lett. **111**, 122503 (2013)

From *H.V. Klapdor-Kleingrothaus et al. Physics Letters B 586 (2004)* we expect to see 6 signal events

Previous claim discarded



Phase II - Upgrade



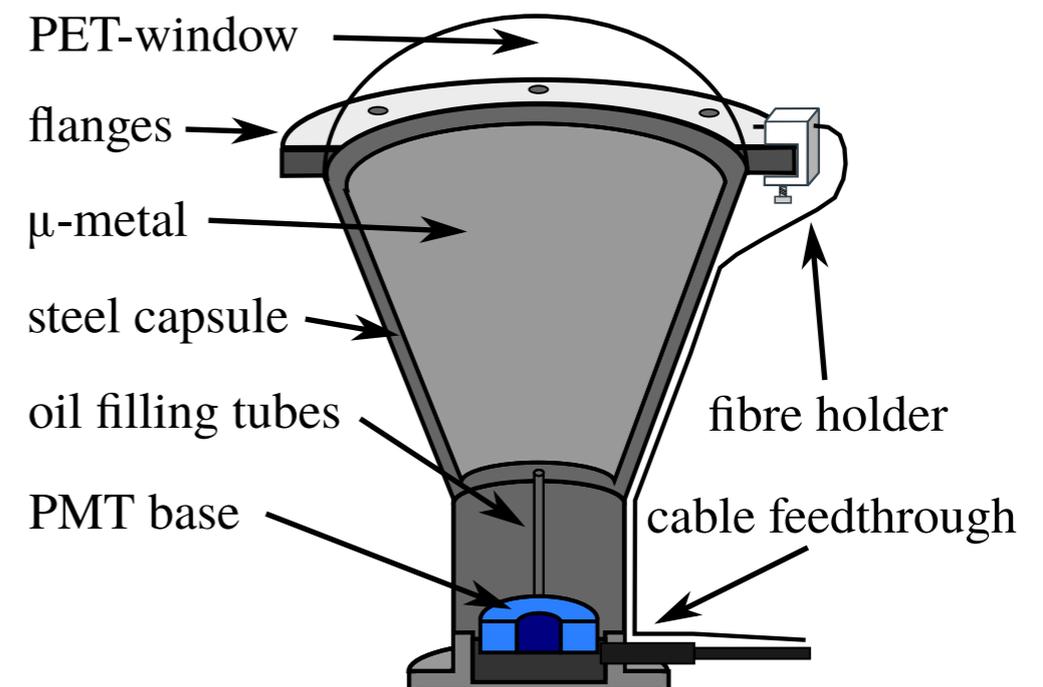
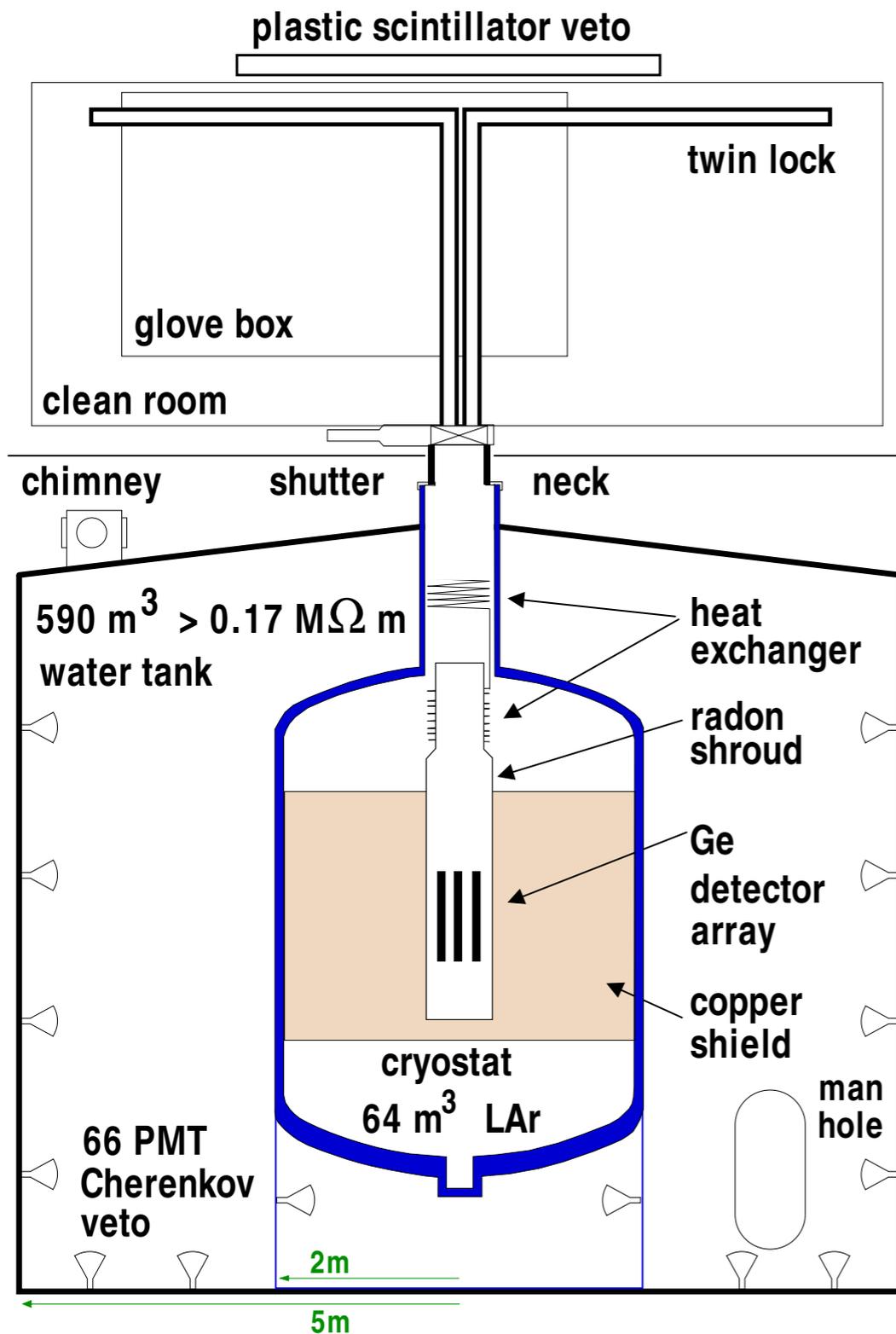
$$T_{1/2}^{0\nu} \simeq \sqrt{\frac{M \cdot t}{B \cdot \Delta E}} \quad [yr]$$

- **More mass:** From the available 37.5 kg enriched germanium 30 new detectors were produced (~20 kg)
- **Lower background:** the goal is 10x lower background
 - New detector holders and new FE electronics
 - ‘BEGe’ detectors for better Pulse Shape Analysis
 - New lock was built to accommodate the LAr veto with PMTs and WLS fibers



Muon veto

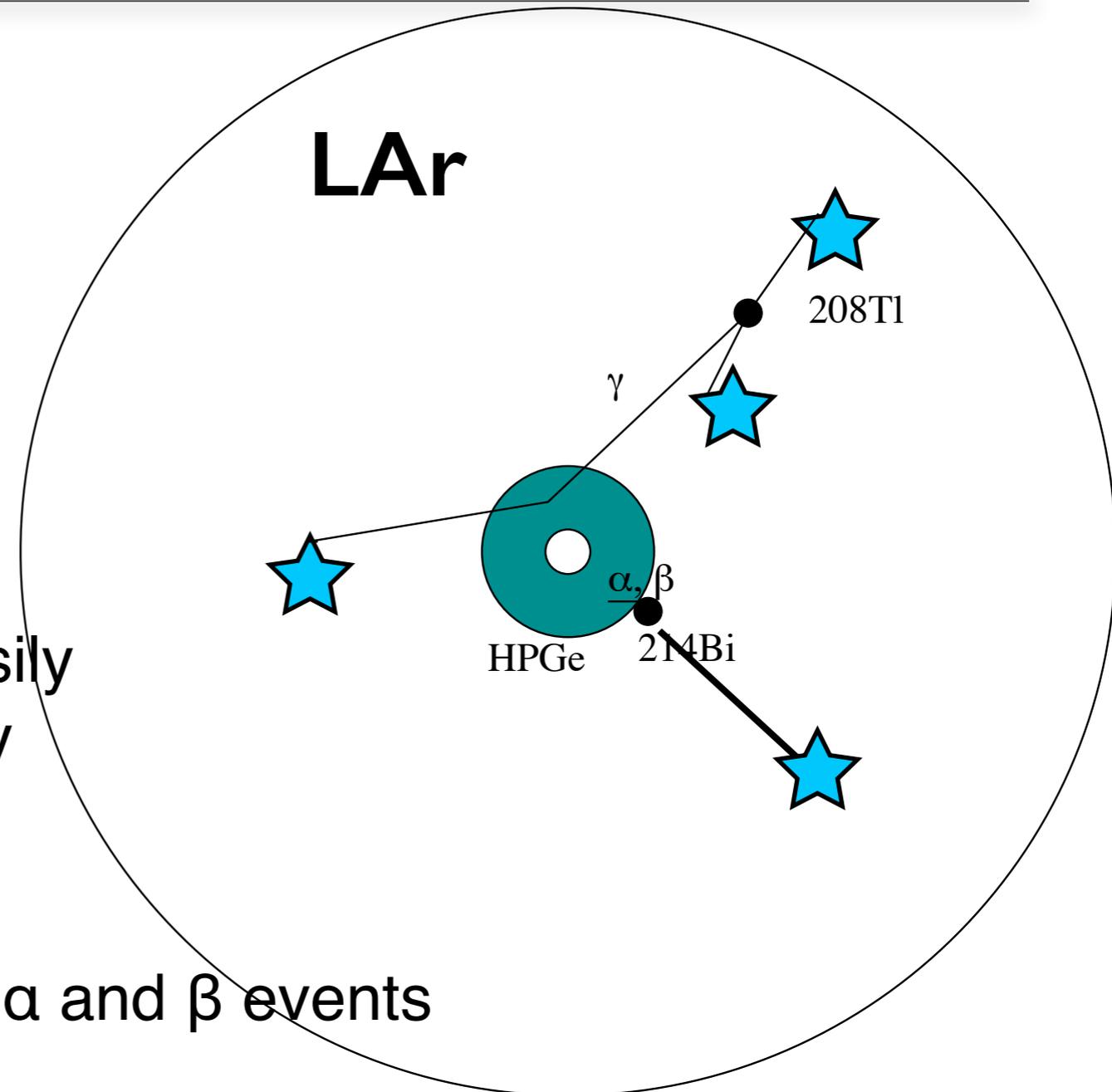
- 66, 8" PMTs in a $\sim 600 \text{ m}^3$ water tank



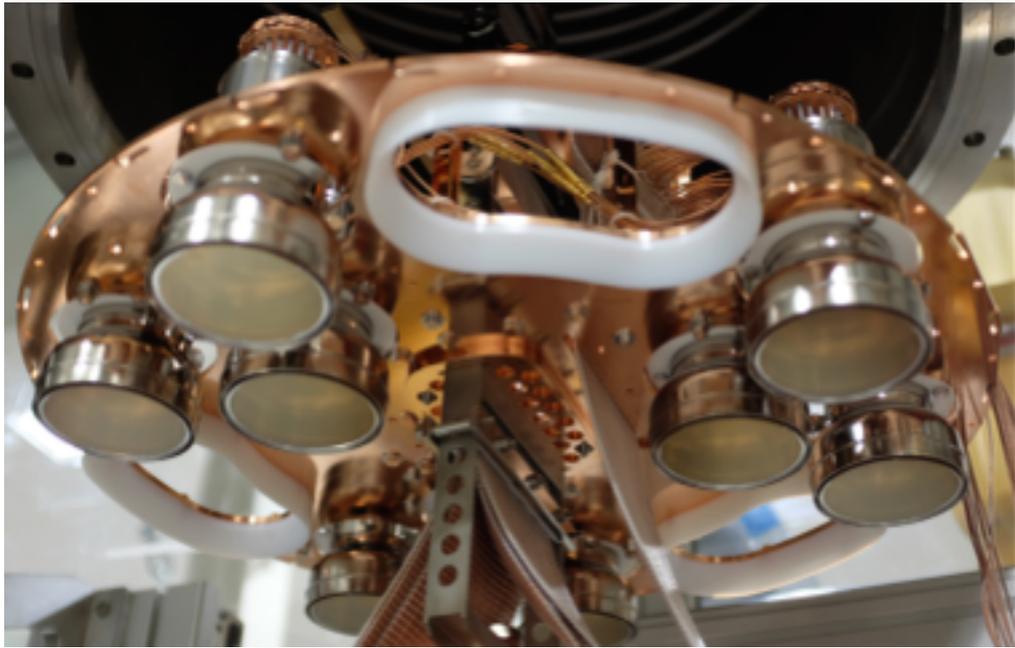
LAr veto - The concept

In the Region of Interest
around 2039 keV

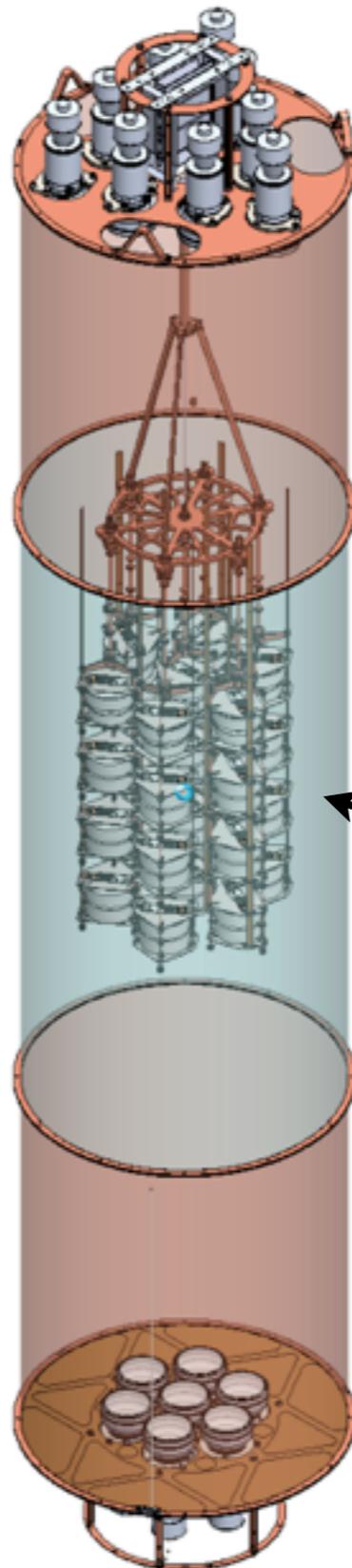
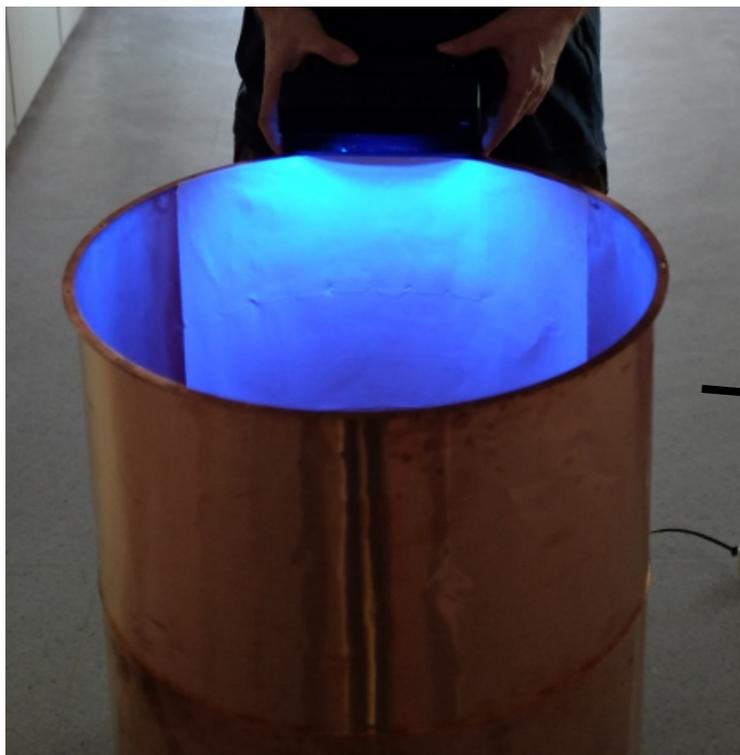
- Nearby ^{208}Tl events can be easily vetoed with very high efficiency
- Veto for ^{214}Bi is less effective
- Does not work well for surface α and β events
 - Veto efficiency in GERDA will strongly depend on the origin of the background



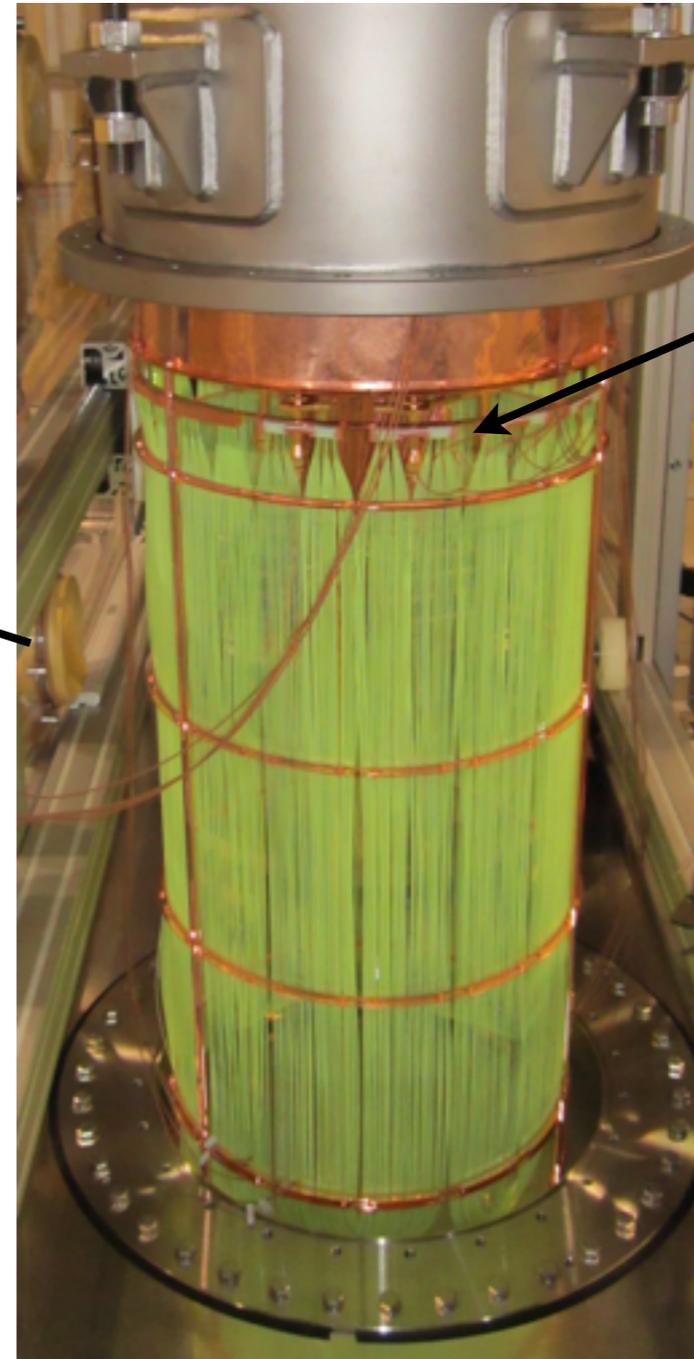
LAr - veto



*Copper "shroud" with
Tetratex reflector coated
with TPB*



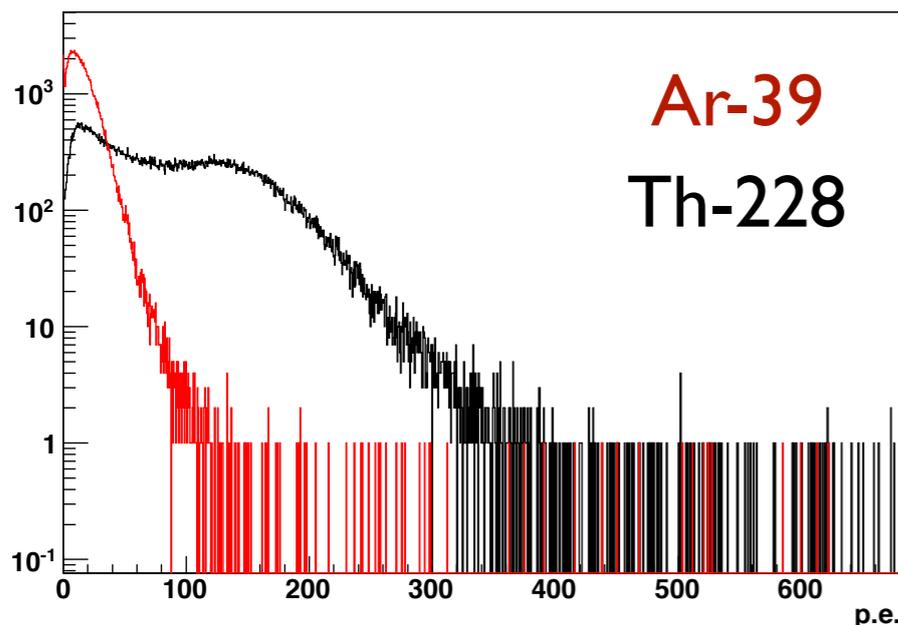
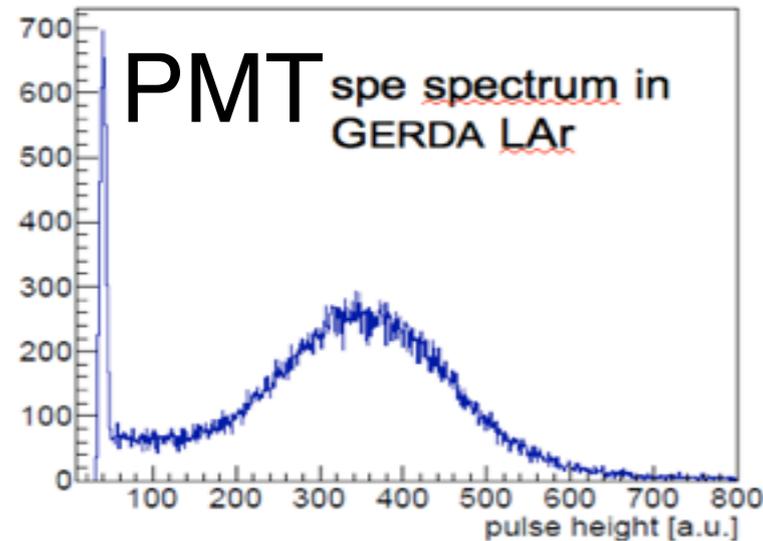
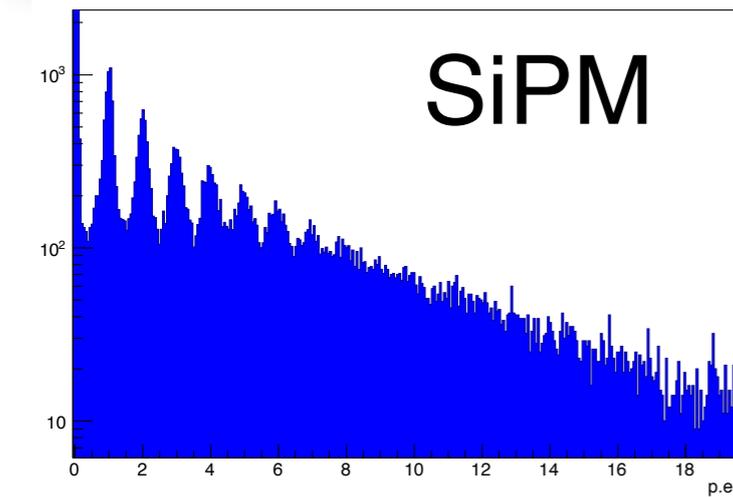
*3" low-background PMT
Hamamatsu R11065-20*



SiPMs

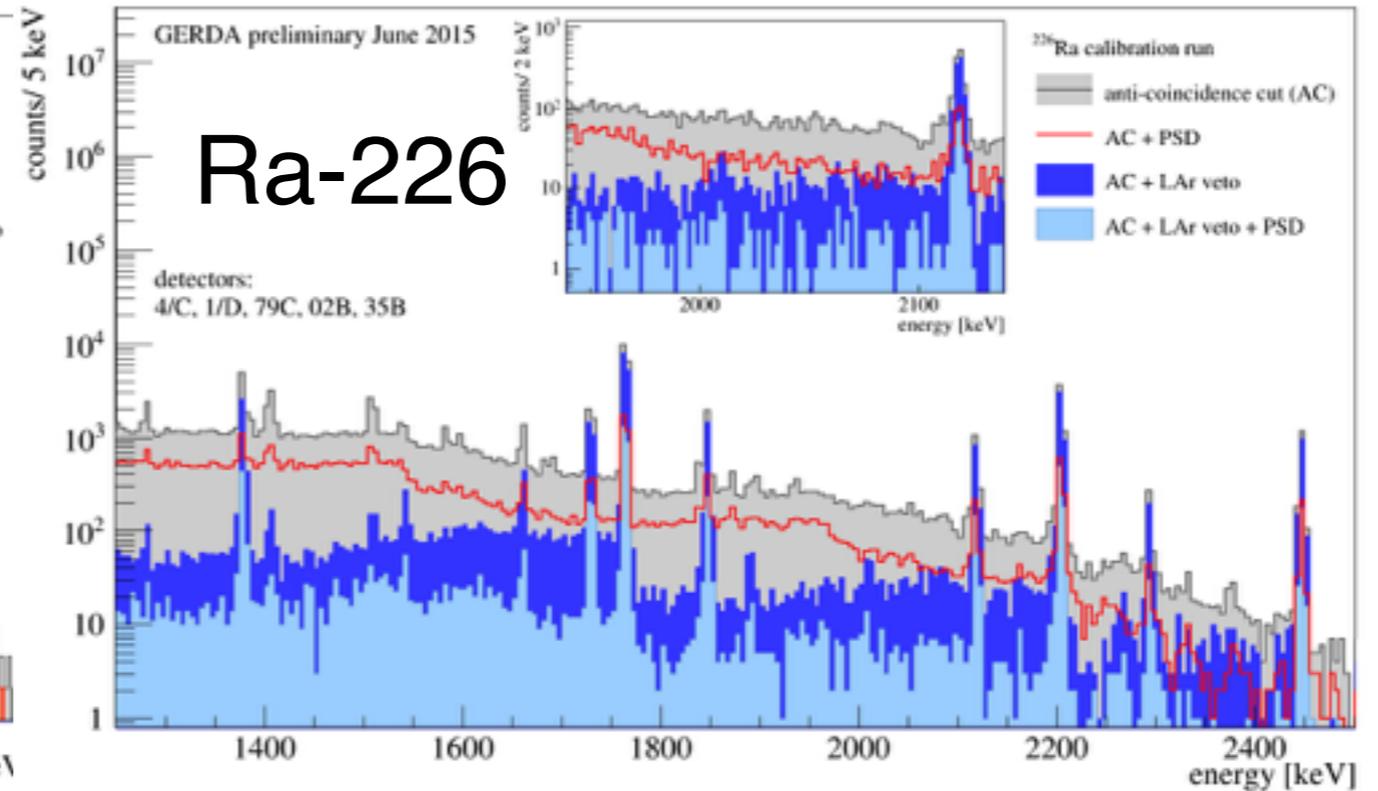
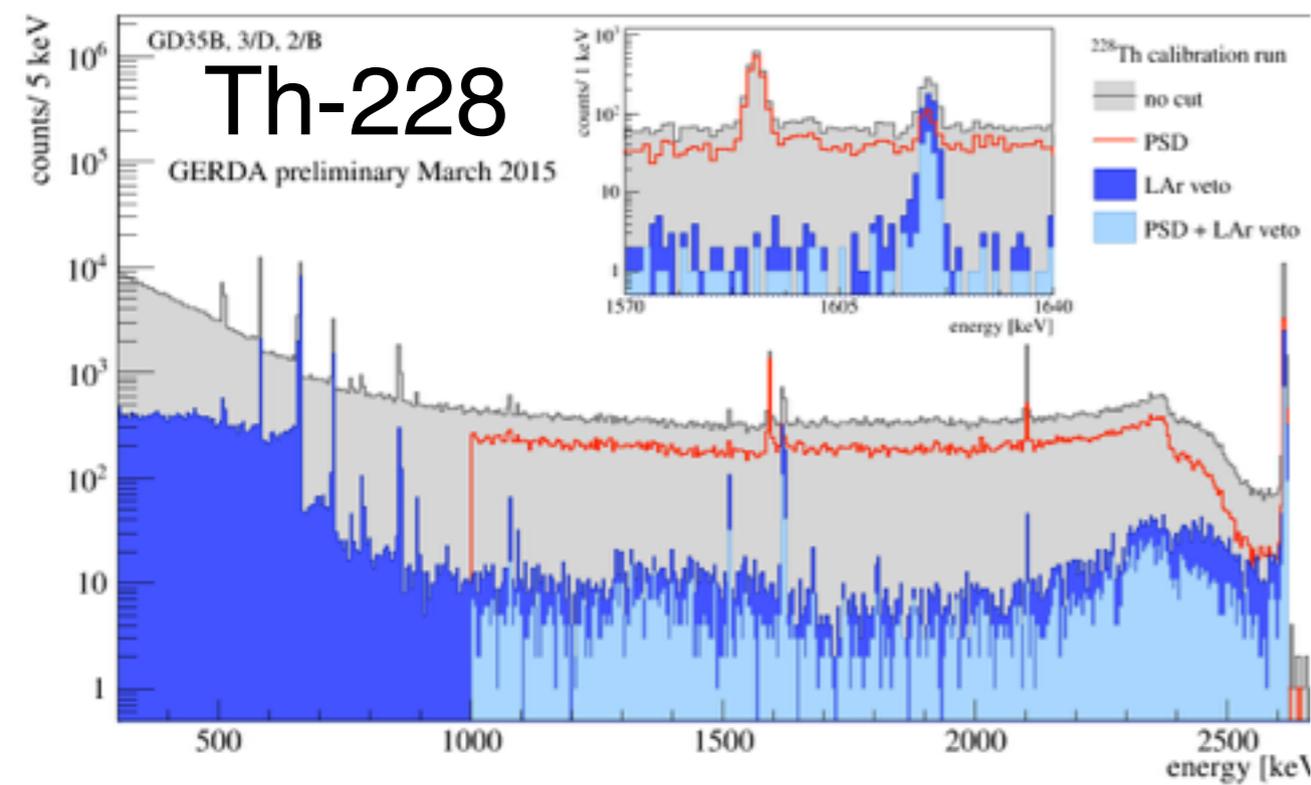
*Fiber "shroud"
800 m WLS
fibre coated
with TPB*

LAr veto commissioning



- “Photo-electron” peaks recognisable in the amplitude spectrum - in both SiPMs and PMTs spectra
- Veto on one photo-electron in any channel
- After single channels calibrated and summed up: light yield: 50 - 60 p.e./MeV - with ²²⁸Th source
- Count rate dominated by ³⁹Ar
- LAr -veto Suppression Factor tested with one detector string with ²²⁸Th and ²²⁶Ra sources

LAr veto commissioning



Suppression of:	Ge Anti-Coincidence	LAr-veto	PSD	LAr + PSD	Acceptance
^{228}Th	1.26 ± 0.01	97.9 ± 3.7	2.19 ± 0.01	344.6 ± 24.5	86.8%
^{226}Ra	1.26 ± 0.01	5.7 ± 0.2	2.98 ± 0.06	29.4 ± 2.5	89.9%

More on SiPMs

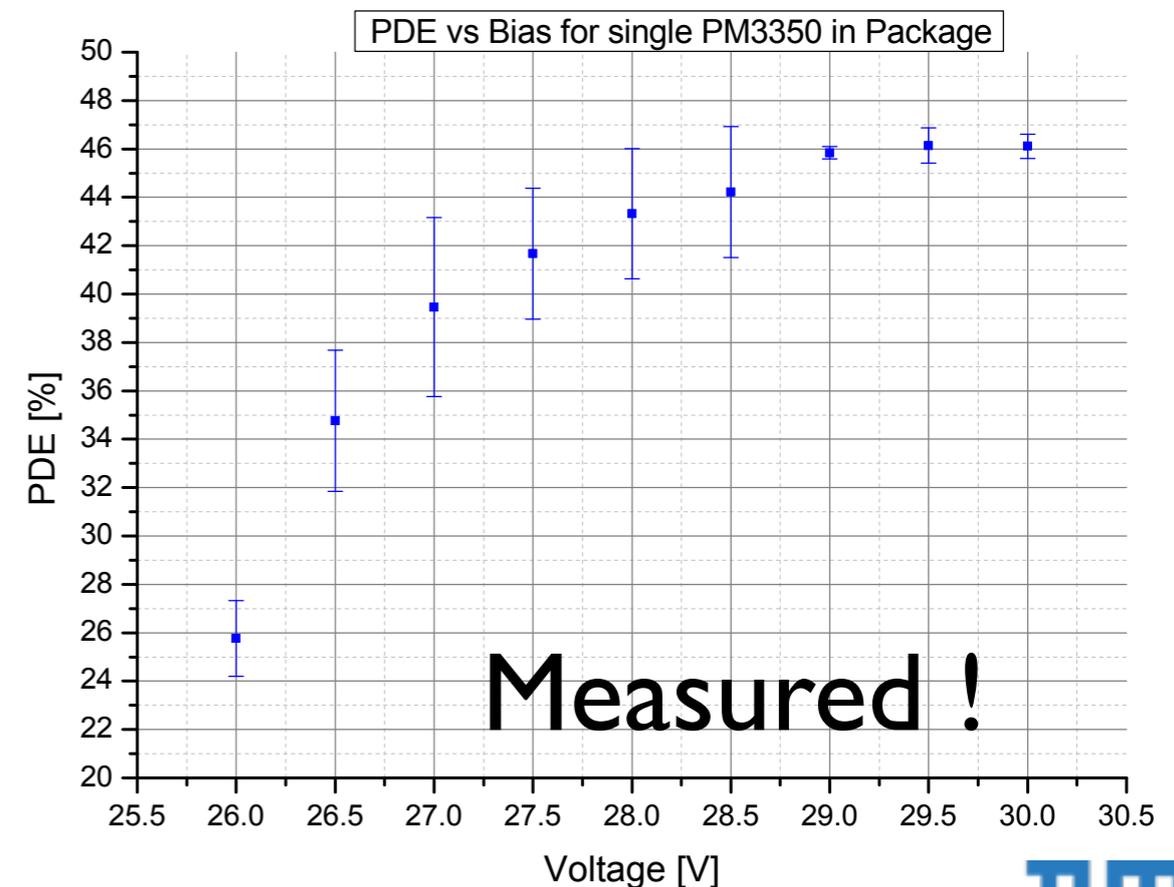
LAr - veto, SiPMs

<i>Element</i>	<i>Conc.</i>	<i>Activity Bq/kg</i>	<i>Background in GERDA cts/(keV kg Yr)</i>
<i>Th</i>	$< 0.25 \text{ ppb}$	$< 1 \times 10^{-3}$	$\sim 10^{-6}$
<i>U</i>	$< 0.25 \text{ ppb}$	$< 3 \times 10^{-3}$	$\sim 10^{-7}$

ICPMS done at LNGS: SiPMs

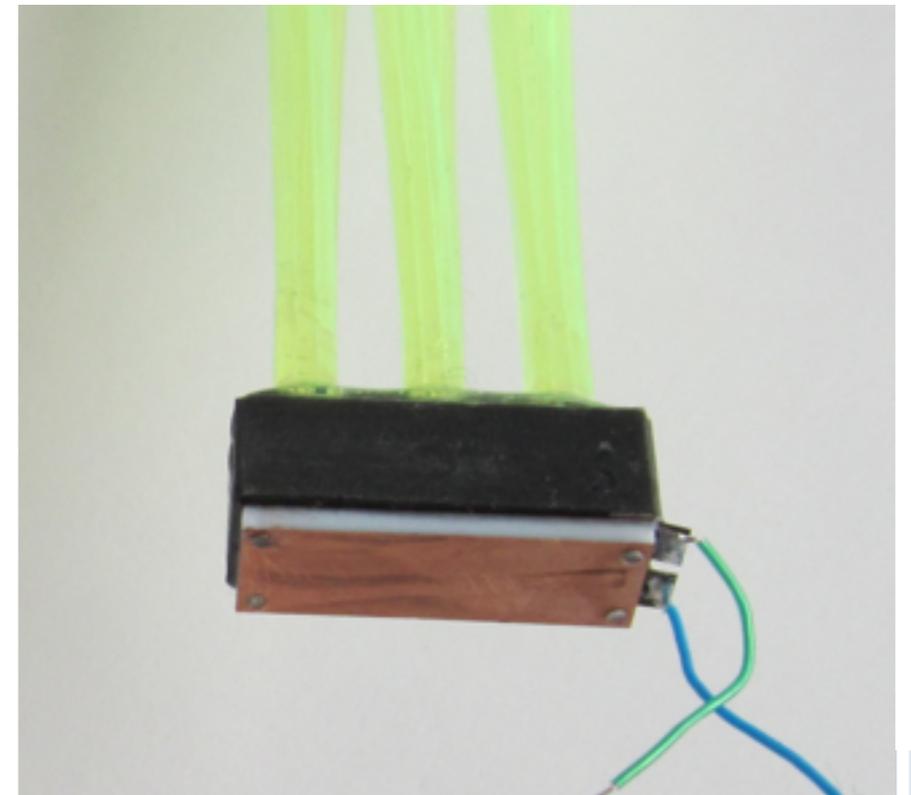
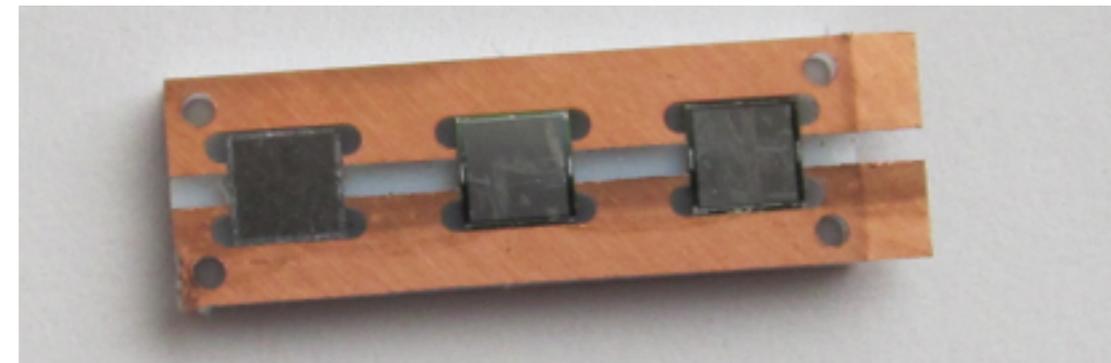
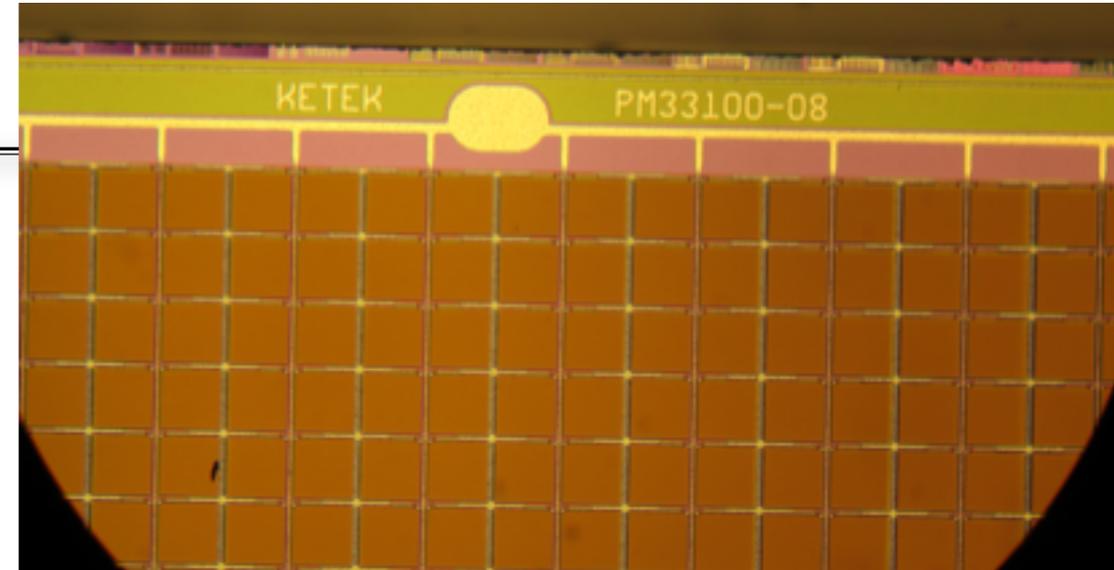
Ketek SiPM in die (3x3 mm, 50 μ m pixel)

- Good match for the size of the WLS fiber
- Small & Silicon = Low background
- High QE, Works at cryogenic temperatures
- Relevant activity for GERDA $< 10 \mu\text{Bq}$
- 1 m² SiPM would have $< 10 \text{ mBq}$ activity

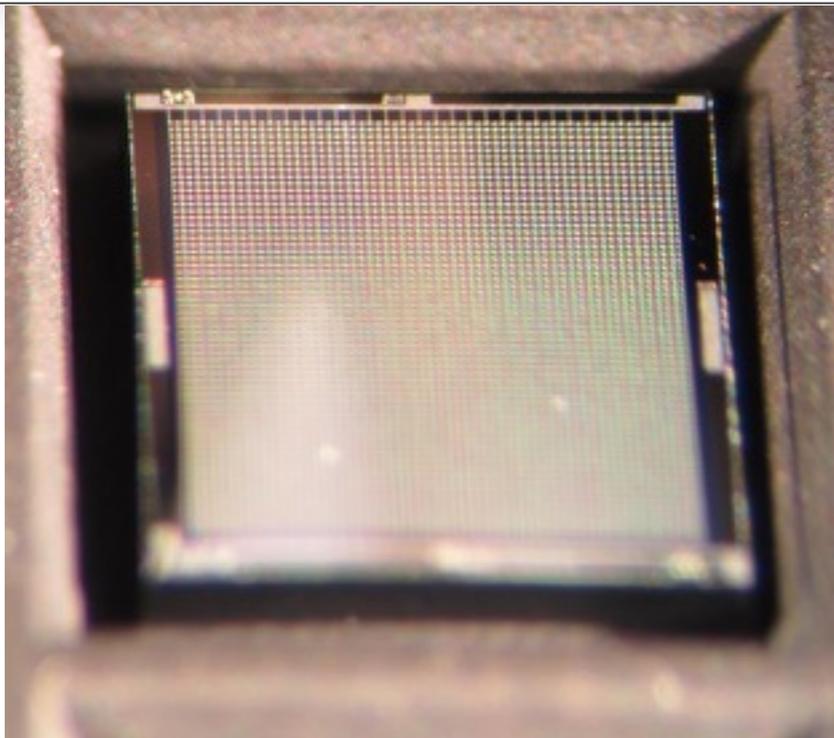


Ketek SiPMs

- *Ketek GmbH the only company to sell SiPMs in die*
- *Self made packaging from radio-pure materials (Cuflon)*
- *3x3 mm², 50 μm and 100 μm pixel size*
- *90 SiPMs to 15 read-out channels*
- *Total sensitive surface in GERDA 8.1 cm²*



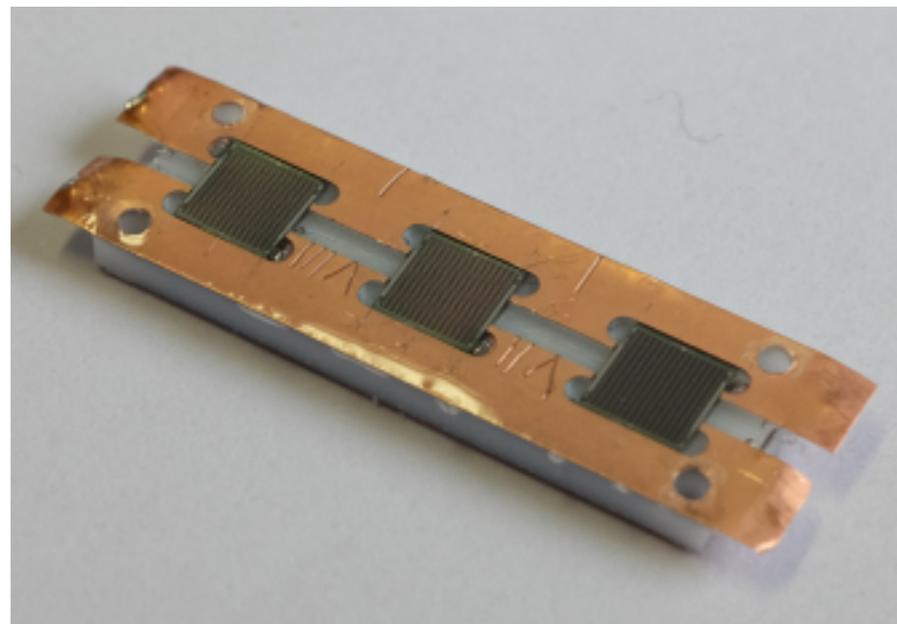
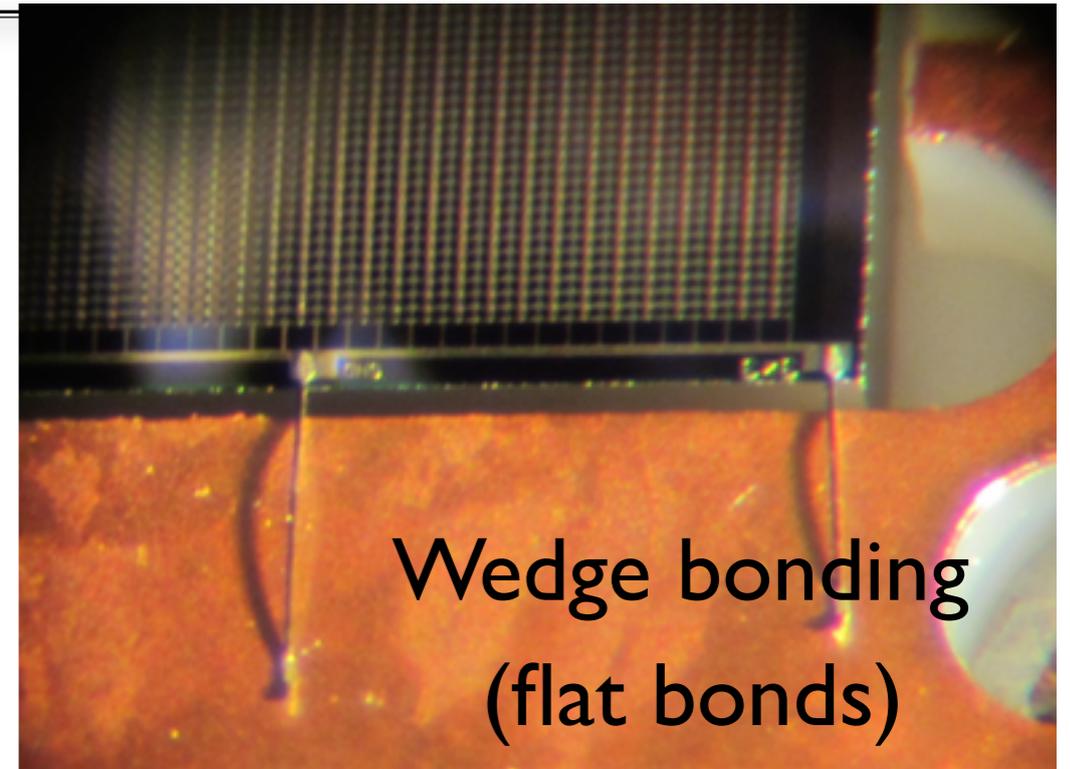
SiPM packaging



Chips in waffle package



Cuflon PCB



transparent epoxy

Arrays of 6 SiPM

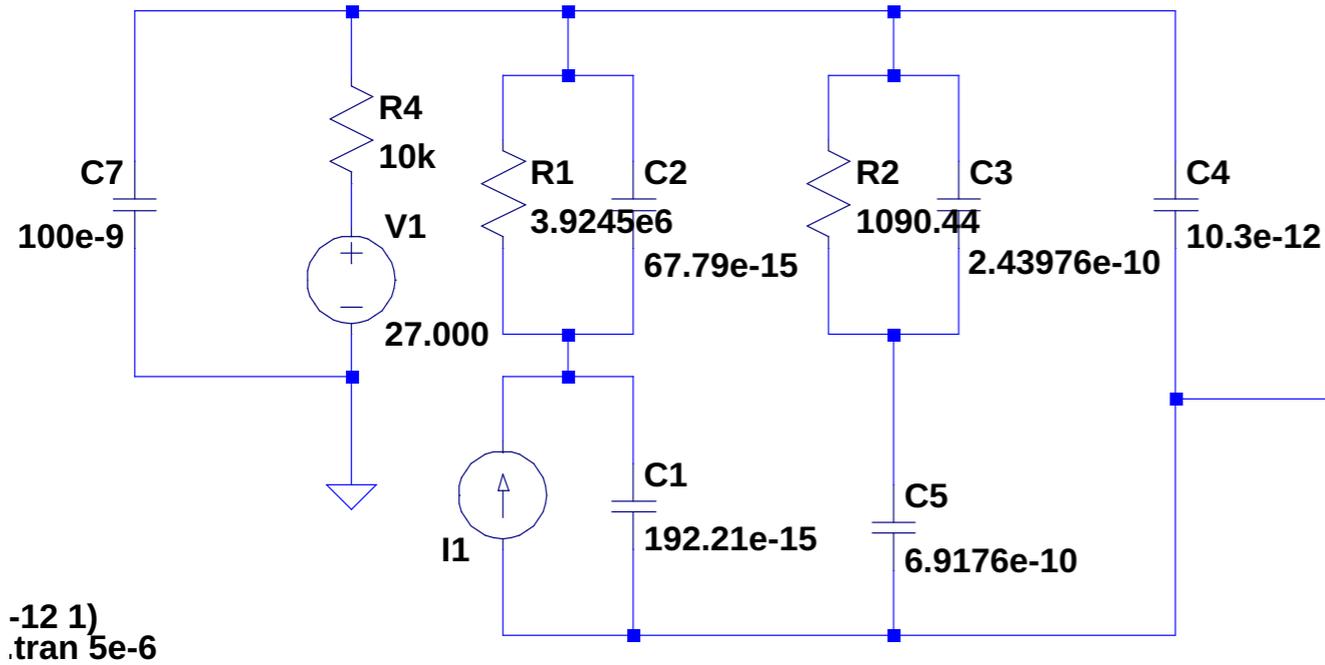


On SiPM packaging

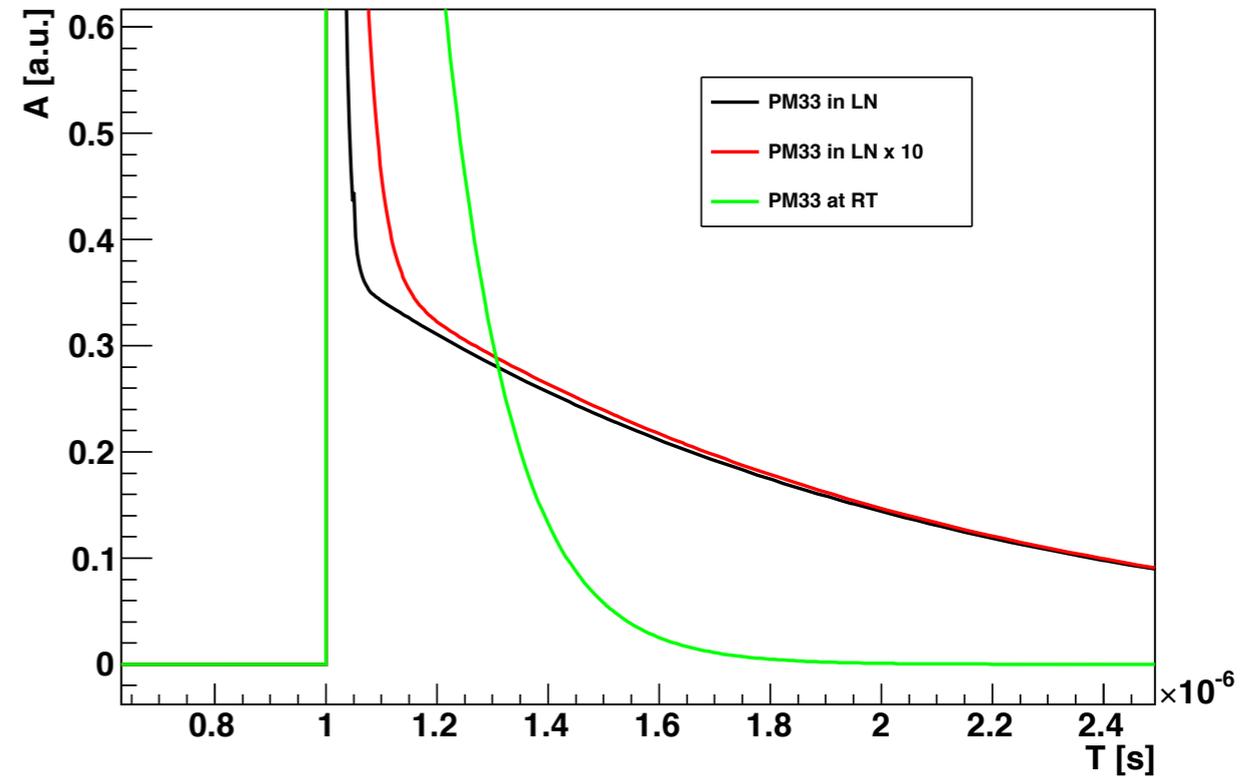
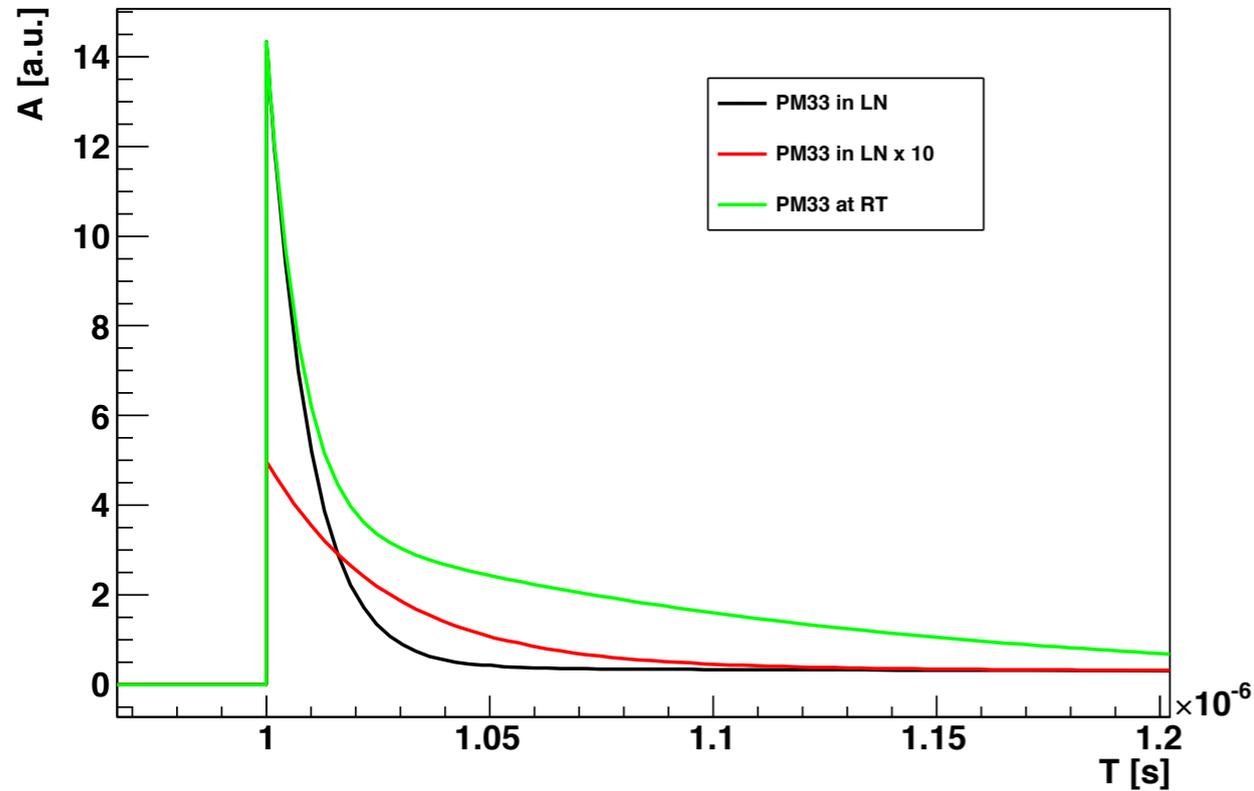
Why bare chips or self made packaging ?

- SiPMs small and made of pure Si - major advantage over PMTs
- allowed materials for low background experiments: silicon, synthetic quartz, electrolytic copper, some plastics
- Bare chips sensitive down to 160 nm (SiO_2 cutoff)
 - direct detection of VUV light might be possible
 - in the future we could have MgF_2 coating (sensitivity down to 120 nm)
- Integration problem: front-end (ASIC) should be close to the chip while maintaining radiopurity - one substrate for all
 - connectors & cables our biggest problems

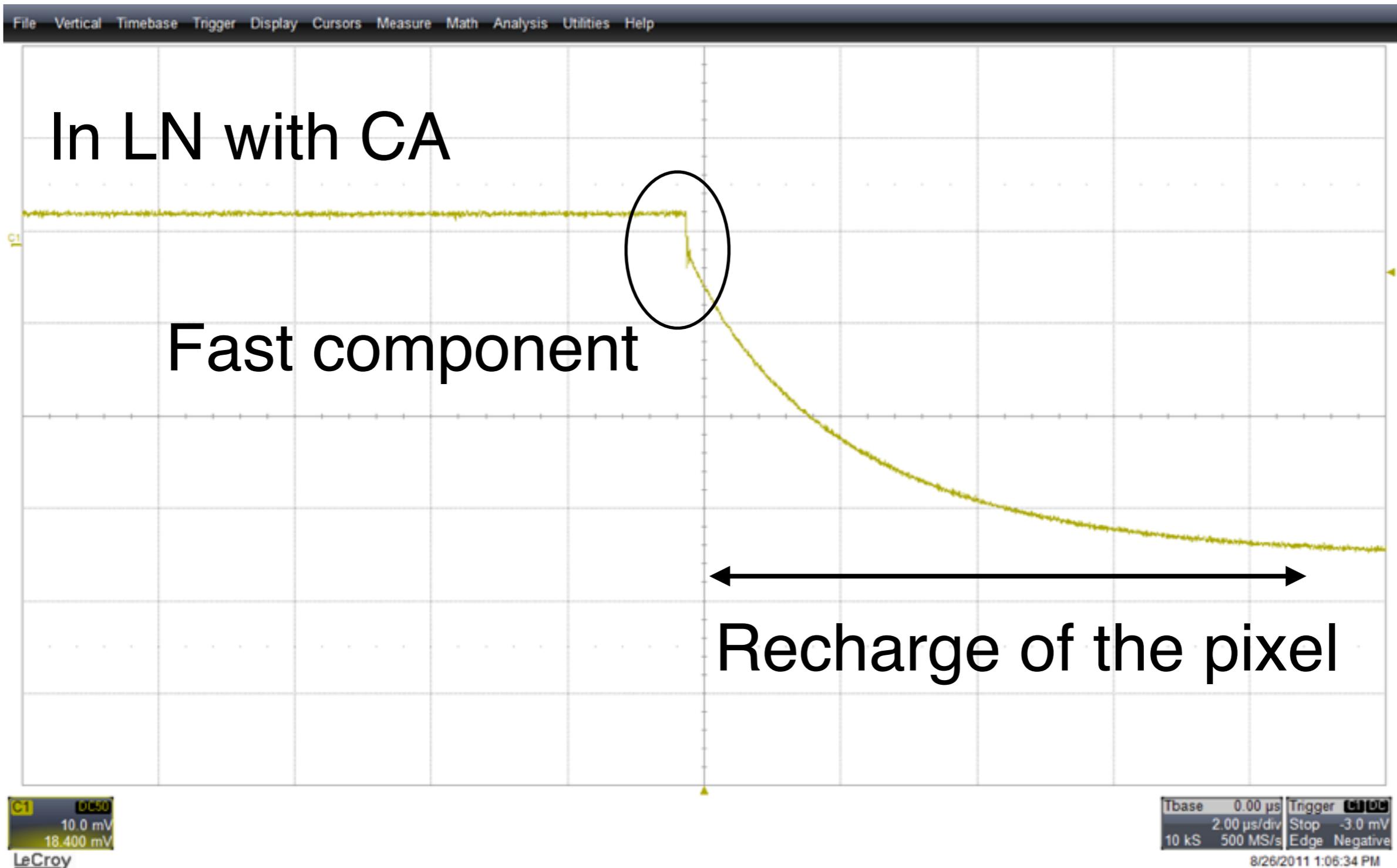
Spice model of the SiPM



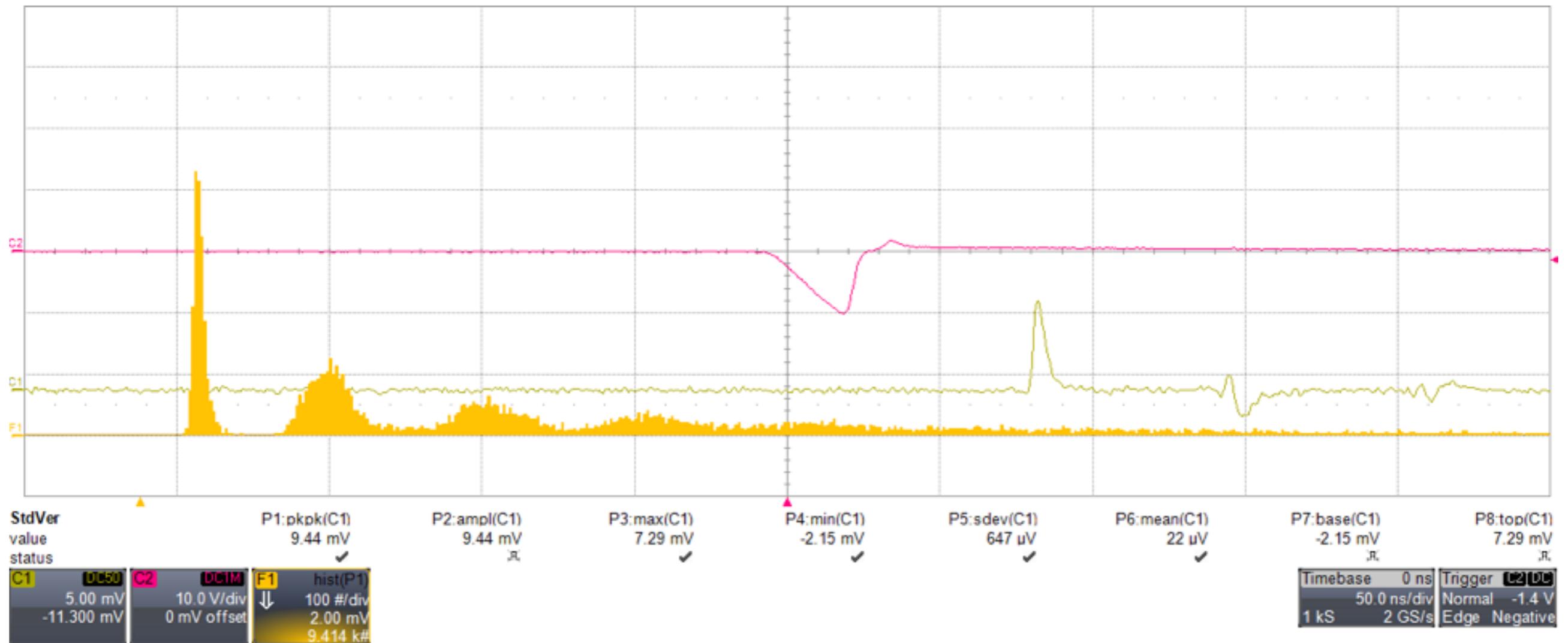
- See for example: NIM A 572 (2007) 416–418
- Model tuned for Ketek SiPMs in LN



Ketek SiPM: Charge integral

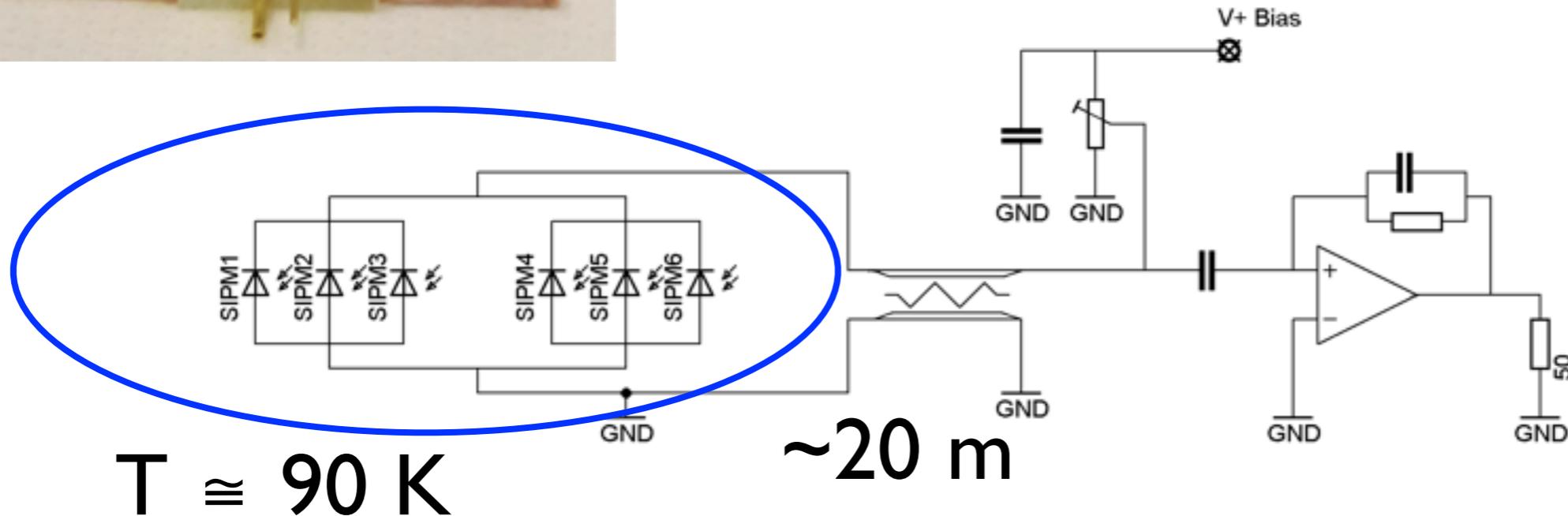
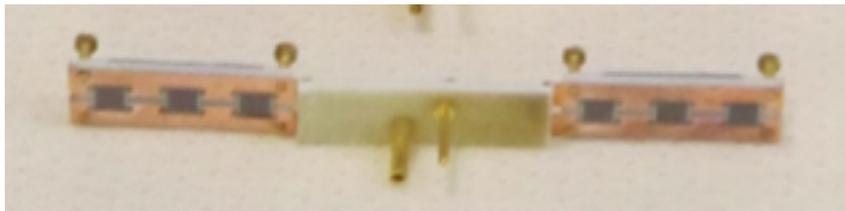


Ketek 100 μm SiPM: Fast pulse

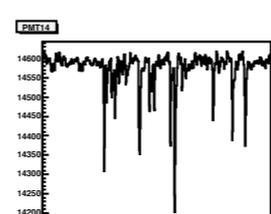
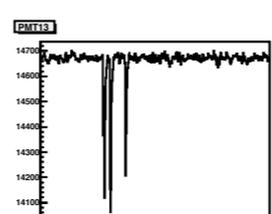
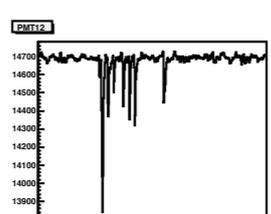
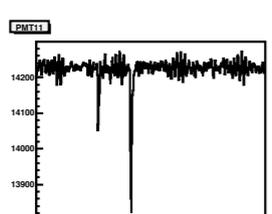
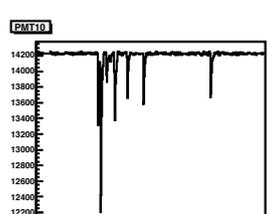
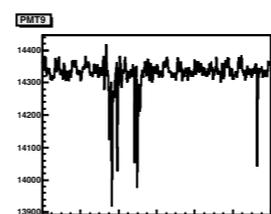
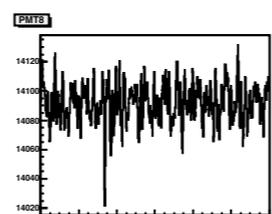
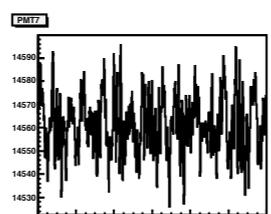
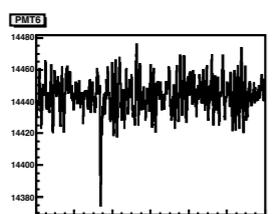
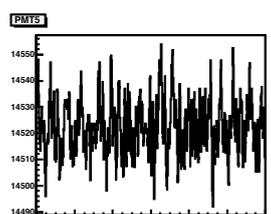
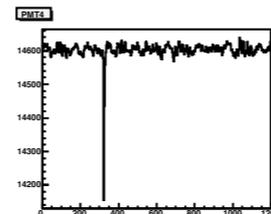
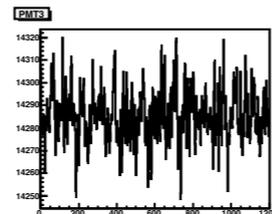
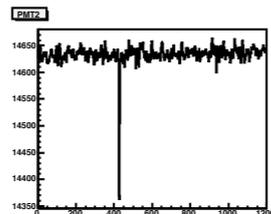
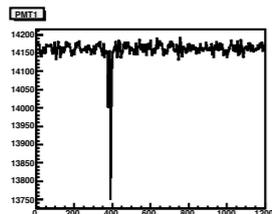
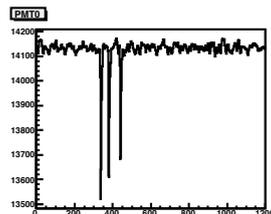
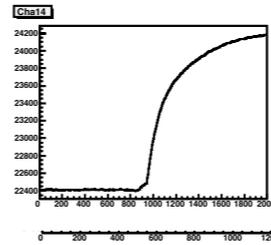
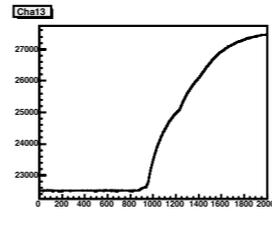
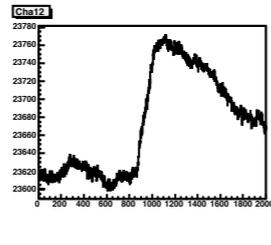
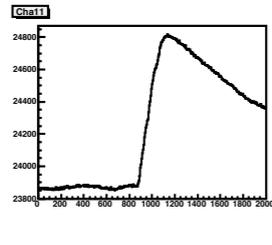
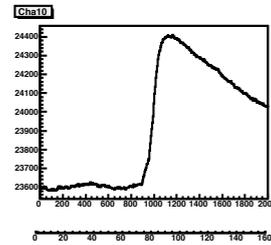
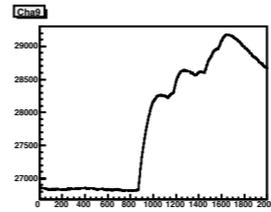
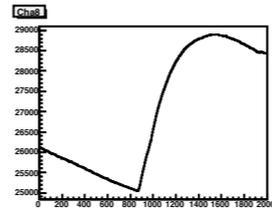
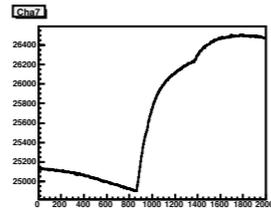
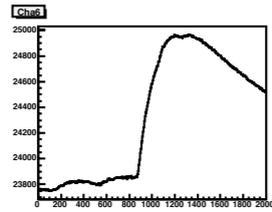
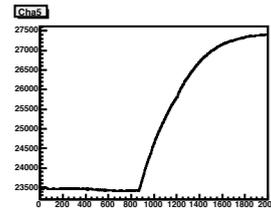
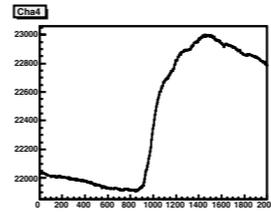
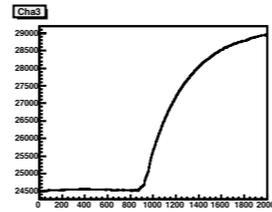
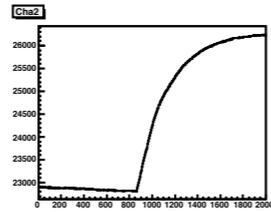
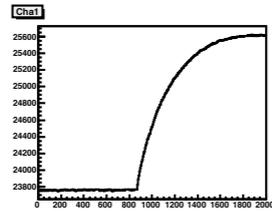
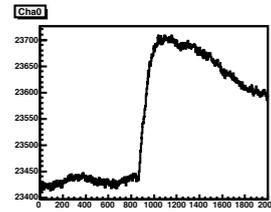
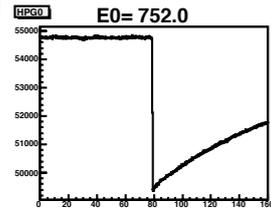


- Fast component: low gain
- Depends on the pixel size (capacity), here 100 μm .
- Single photon (pixel) resolution preserved

GERDA SiPM read-out



- 6, $3 \times 3 \text{ mm}^2$ SiPM in paralel: no electronics in LAr!
- 20 m, 50Ω cable to the amplifier
- Read-out from the ‘high voltage’ side

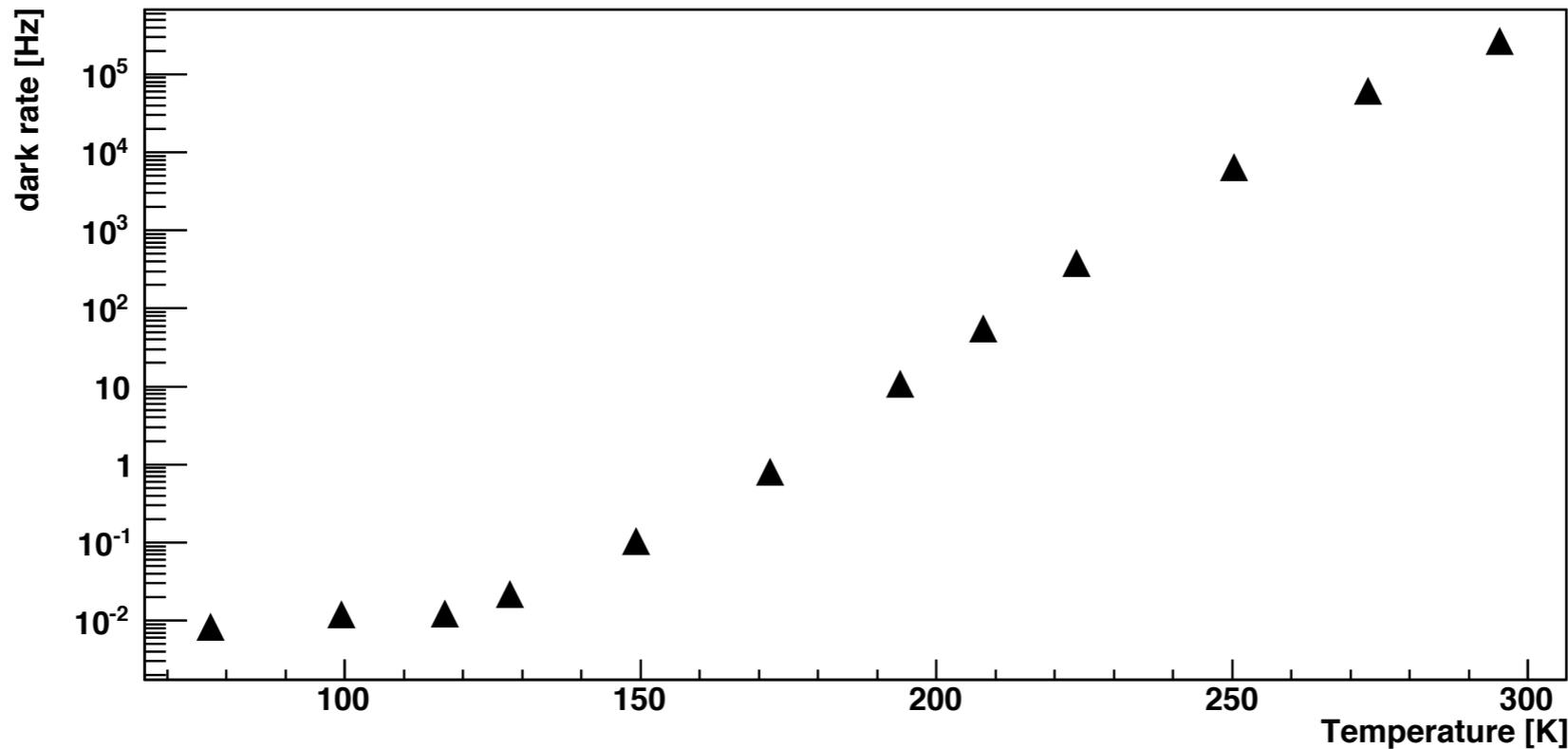


HPGe - channel
160 μ s - traces

15- SiPM channels
80 μ s - traces
80 ns resolution

16 - PMT channels
12 μ s traces
10 ns resolution

SiPM Dark Rate



- Measured with Hamamatsu MPPC 50 μm pixel 10⁻² Hz/mm² in **LN**
- Ketek 3x3 mm, 50 μm , ~ 1 Hz = 10⁻¹ Hz/mm²
- 100 cm² SiPM array would have ~ 1 kHz DR in **LAr**
 - In **LXe** the DR is 10 kHz or 100 kHz ?
- How does the DR depend on SiPM design, production process, wafer quality?
 - ➔ Systematic study needed

Future ...

Demand:

- Gerda - like - 200 kg HPGe experiment (maybe 1 ton experiment ?)
- probably the same technology as GERDA

Other Cryo-liquid experiments:

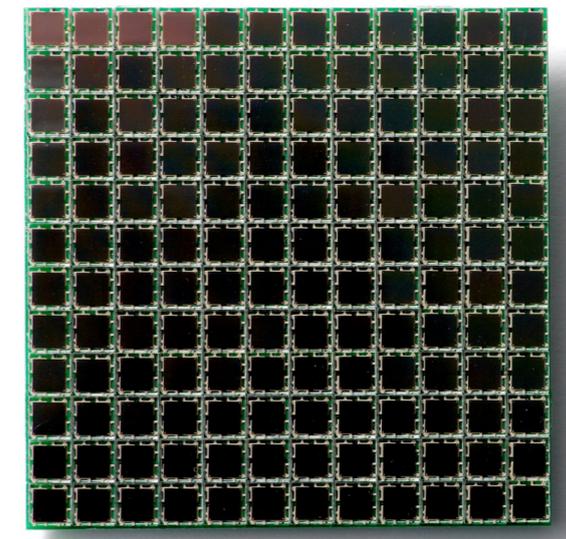
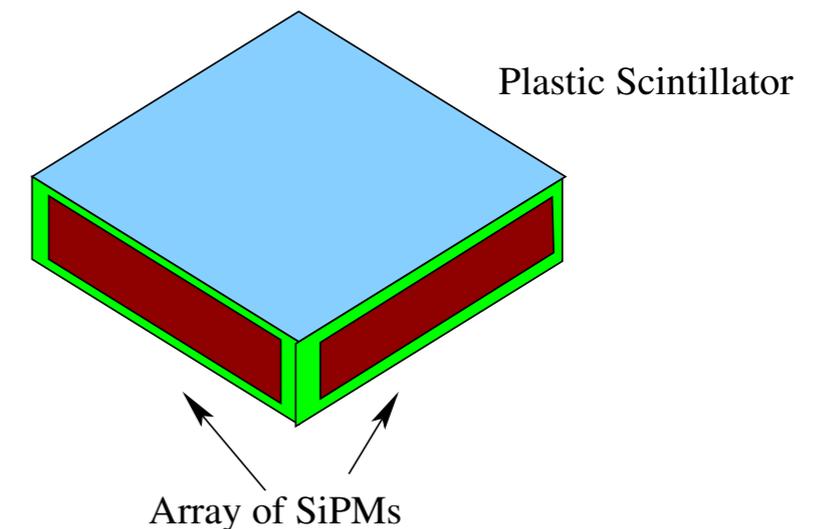
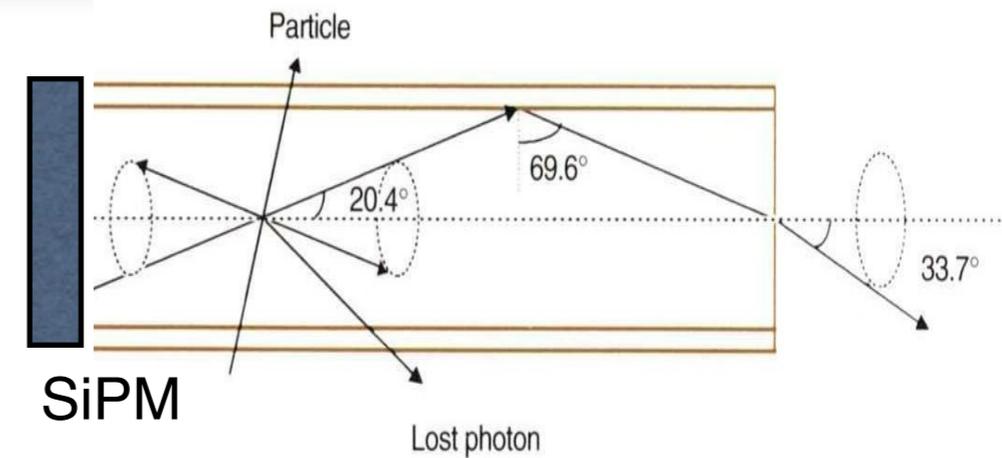
- Xe - double beta decay (nEXO), dark matter Xe-TPC. (Xe-1t, LZ)
- Ar - dark matter: Ar-TPC, HEP: DUNE

Offer:

- PMTs still have reliability problems in LAr
- Low background experiments will have to phase out PMTs
- SiPMs are OK but too small

Possible technology

- Instrument tons of LAr with WLS fibers or scintillator bars - with SiPM read-out
- Max. 14% trapping efficiency, total efficiency $\sim 5\%$ for a narrow wavelength
- 2D WLS 'fiber': WLS plates with SiPMs on the edges
- trapping efficiency up to 30% possible at the right wavelength, 10% det. eff.
- Highest possible p.d.e. \Rightarrow large SiPM array
- 40 - 60 % p.d.e.



ASIC for large SiPM array

- Sum up the signal from 10÷100 cm² SiPM without adding up the capacity. (“amplifier” with ~100 inputs and 1 output channel)
- drive 50 Ω line (analog signal preferred)
- Should work at LN temperature
- available in ‘die’ (radiopurity requirement)
- ~mW power consumption, single rail power line (derived from SiPM bias)
- integrated bias circuit for ~100 SiPMs: equalise gain between SiPMs, current limit, shut down broken SiPM

We don't need !

- signal rise time better than 10 ns
- dynamic range > 1000 / channel